### **Bilkent University**

# **Electrical and Electronics Department**

## **EE313-02 Lab 3 Preliminary Report:**

# "Single-Supply Push-pull Class-B Power Amplifier"

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### **Introduction:**

This lab's main aim is designing a single – supply push – pull class – b power amplifier by using 2 different NPN transistors (BC238 and BD135), 2 different PNP transistors (BC308 and BD136) and 1 OPAMP (LM358). Load resistance is  $33\Omega$  and supply voltage is 24V. My Bilkent ID in modulo 7 is 6. Therefore, my design should operate with sinusoidal voltages with a gain equal to 26 dB.

### **Simulation & Analysis:**

Here you can see my final circuit for the lab (**Figure 1**):

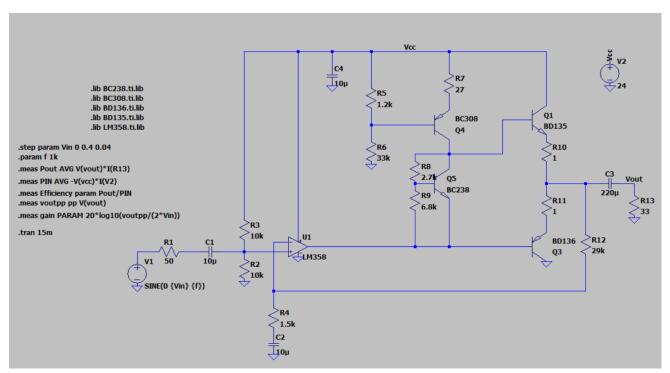
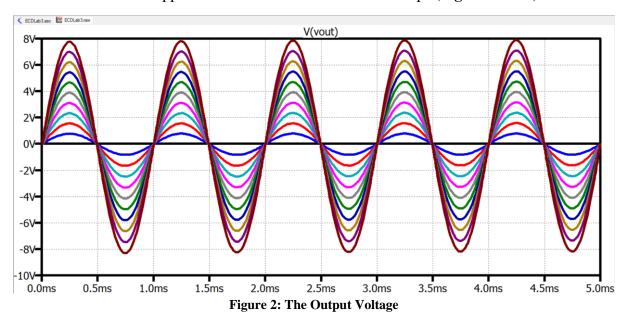


Figure 1: The Amplifier Circuit

Here you can see the output voltage and the currents on the emitters of BD135 and BD136 when Vin is stepped from 0 Volts to 0.4 Volts in 11 steps (**Figures 2 to 4**):



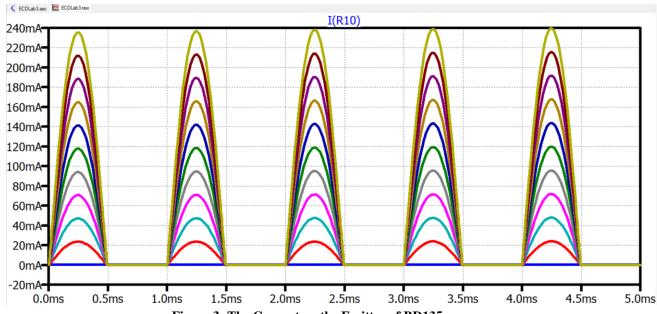
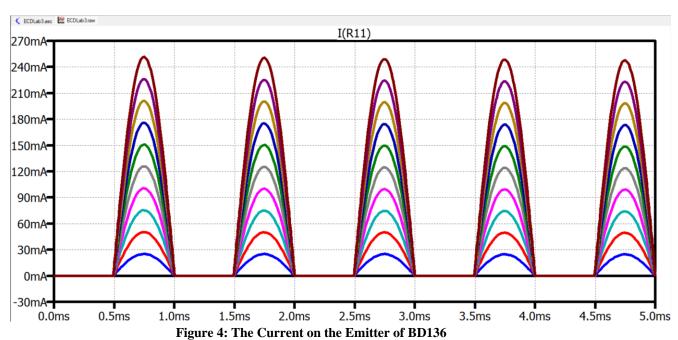


Figure 3: The Current on the Emitter of BD135



Here are the specifications that were given to us in the lab manual (**Figure 5**):

#### Specifications:

- 1. The amplifier should deliver at least 0.95W power to a  $33\Omega$  resistance ( $16V_{pp}$  to a  $33\Omega$  power resistor) at 1KHz with the chosen gain value.
- 2. The harmonics (the highest is possibly the third harmonic) at the 0.95W output power level should be at least 40 dB lower than the fundamental signal at 1 KHz.
- 3. The power consumption at quiescent conditions should be less than 500mW.
- 4. The amplifier's efficiency (output power/total supply power) should be at least 40% at max power output (0.95W) at 1KHz.
- 5. The -3dB bandwidth of the amplifier should be at least 150Hz to 15KHz.

Figure 5: The Specification of the Circuit

Now let's dive deep in each criterion:

#### **Criterion 1:**

Here you can see the power at the output when the gain is 26dB (**Figures 6 & 7**). When Vin is 0.4 Volts, the power at the output is 978mW.

| Measurement: | pout             |           |       |
|--------------|------------------|-----------|-------|
| step         | AVG(v(vout)*i(r) | 13)) FROM | TO    |
| 1            | 1.26721e-20      | 0         | 0.005 |
| 2            | 0.0097743        | 0         | 0.005 |
| 3            | 0.0390972        | 0         | 0.005 |
| 4            | 0.0879686        | 0         | 0.005 |
| 5            | 0.156413         | 0         | 0.005 |
| 6            | 0.244411         | 0         | 0.005 |
| 7            | 0.351964         | 0         | 0.005 |
| 8            | 0.479073         | 0         | 0.005 |
| 9            | 0.625776         | 0         | 0.005 |
| 10           | 0.792083         | 0         | 0.005 |
| 11           | 0.978179         | 0         | 0.005 |

Figure 6: The Power on the Output

| Measurement: | gain                     |  |
|--------------|--------------------------|--|
| step         | 20*log10(voutpp/(2*vin)) |  |
| 1            | inf                      |  |
| 2            | 26.1279                  |  |
| 3            | 26.126                   |  |
| 4            | 26.1302                  |  |
| 5            | 26.1306                  |  |
| 6            | 26.13                    |  |
| 7            | 26.1237                  |  |
| 8            | 26.132                   |  |
| 9            | 26.128                   |  |
| 10           | 26.1319                  |  |
| 11           | 26.1307                  |  |

Figure 7: The Gain of the Circuit

#### Criterions 3 & 4:

Here you can see the power at the input, output and the efficiency of the circuit (**Figure 8**). As expected in criterion 3, the input power -when Vin is zero- is 197mW and it is well below 500mW. As expected in criterion 4, the efficiency is 49.6% and it is well above 40% when the power at the output is 950mW.

| Measurement: p | oout                 |      |       |
|----------------|----------------------|------|-------|
| step           | AVG(v(vout) *i(r13)) | FROM | TO    |
| 1              | 1.26721e-20          | 0    | 0.005 |
| 2              | 0.0097743            | 0    | 0.005 |
| 3              | 0.0390972            | 0    | 0.005 |
| 4              | 0.0879686            | 0    | 0.005 |
| 5              | 0.156413             | 0    | 0.005 |
| 6              | 0.244411             | 0    | 0.005 |
| 7              | 0.351964             | 0    | 0.005 |
| 8              | 0.479073             | 0    | 0.005 |
| 9              | 0.625776             | 0    | 0.005 |
| 10             | 0.792083             | 0    | 0.005 |
| 11             | 0.978179             | 0    | 0.005 |
| Measurement: p | oin                  |      |       |
| step           | AVG(-v(vcc)*i(v2))   | FROM | TO    |
| 1              | 0.19751              | 0    | 0.005 |
| 2              | 0.37437              | 0    | 0.005 |
| 3              | 0.551975             | 0    | 0.005 |
| 4              | 0.729542             | 0    | 0.005 |
| 5              | 0.907059             | 0    | 0.005 |
| 6              | 1.08453              | 0    | 0.005 |
| 7              | 1.26194              | 0    | 0.005 |
| 8              | 1.43932              | 0    | 0.005 |
| 9              | 1.6167               | 0    | 0.005 |
| 10             | 1.79394              | 0    | 0.005 |
| 11             | 1.97124              | 0    | 0.005 |
| Measurement: e | efficiency           |      |       |
| step           | pout/pin             |      |       |
| 1              | 6.41591e-20          |      |       |
| 2              | 0.0261087            |      |       |
| 3              | 0.0708314            |      |       |
| 4              | 0.120581             |      |       |
| 5              | 0.172439             |      |       |
| 6              | 0.22536              |      |       |
| 7              | 0.278906             |      |       |
| 8              | 0.332846             |      |       |
| 9              | 0.387069             |      |       |
| 10             | 0.441532             |      |       |
| 11             | 0.496225             |      |       |

Figure 8: The efficiency of the Circuit, Pin and Pout

### **Criterion 5:**

Here you can see the gain of the amplifier and the output voltage when the frequency is 150Hz, 1.5kHz and 15kHz (**Figure 9**). As expected, the gain at 150Hz and 15kHz is well above the –3dB(23dB) limit.

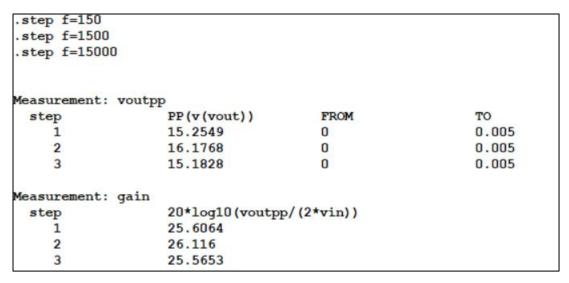


Figure 9: The Gain and Vout when Frequency Changes

#### **Criterion 2:**

Here is the FFT analysis of Vout when Vin is 0.4 Volts (**Figures 10 & 11**). The highest harmonic is the fifth harmonic at 5kHz. The difference in dB is 58.08dB which is well above 50dB as expected.

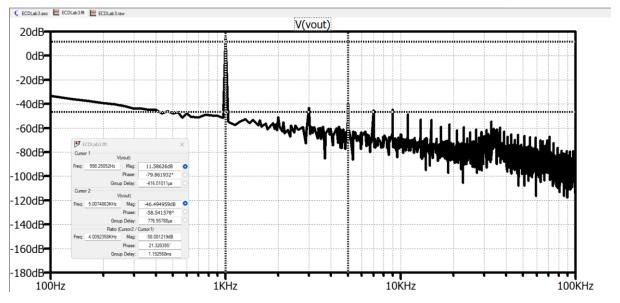


Figure 10: The FFT Analysis of Vout

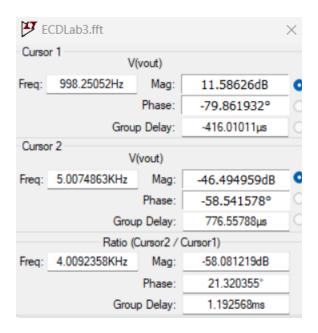


Figure 11: The Difference between the Fundamental Signal and Highest Harmonic being 58.08dB

#### **Conclusion:**

This lab's main aim was designing a single – supply push – pull class – b power amplifier by using 2 different NPN transistors (BC238 and BD135), 2 different PNP transistors (BC308 and BD136) and 1 OPAMP (LM358). Load resistance was  $33\Omega$  and supply voltage was 24V. My Bilkent ID in modulo 7 was 6. Therefore, my design should have operated with sinusoidal voltages with a gain equal to 26 dB.

The design and the simulation were complete. All the criteria were met. The lab was a total success.